

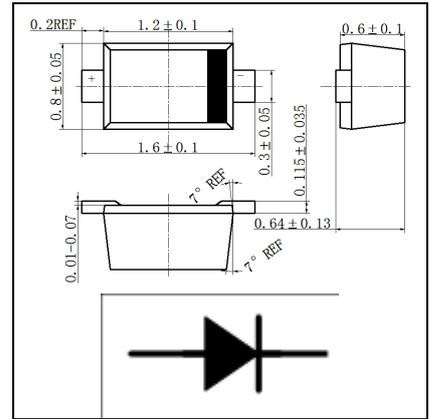
SOD-523 Plastic-Encapsulate Diodes

RB520S30 Schottky Barrier Diode

Features

- Low Forward Voltage Drop
- Flat Lead SOD-523 Small Outline Plastic Package
- Matte Tin(Sn) Lead Finish

Marking: B



Maximum Ratings (T_a=25°C unless otherwise noted, Single Diode)

Symbol	Parameter	Value	Unit
V _{RM}	Repetitive Peak Reverse Voltage	30	V
I _{F(AV)}	Average Rectified Output Current	200	mA
I _{FSM}	Peak Forward Surge Current (At 8.3ms single half sine-wave)	1	A
P _D	Power Dissipation	200	mW
T _J	Junction Temperature	125	°C
T _{stg}	Storage Temperature range	-55 to +125	°C

Electrical Characteristics (T_a=25°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _(BR)	Reverse voltage	I _R = 500μA	30			V
V _F	Forward voltage	I _F = 200mA			0.6	V
I _R	Reverse Leakage current	V _R = 10V			1	μA

Typical Characteristics

